

Challenges Facing the High Temperature Electronics Industry in the Event of Restrictions on High-Pb Solders

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Introduction

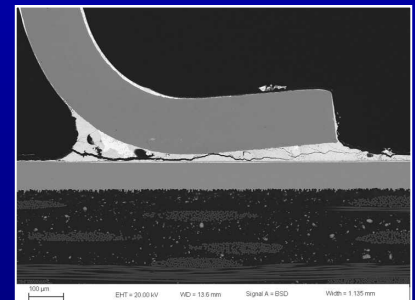
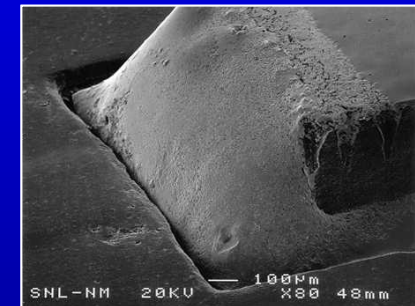
- ◆ The exploration and operation of both renewable (geothermal) and non-renewable (fossil fuel) energy sources will rely heavily upon electronic sensors and down-hole data logging equipment.
 - **Cost-effective exploration of new reserves**
 - **Real-time monitoring of down-hole pressure and temperature conditions.**
 - Maximize production
 - Optimize preventive maintenance
 - Prevent inadvertent site shutdowns or worse, environmental damage



Courtesy of NASA

Introduction

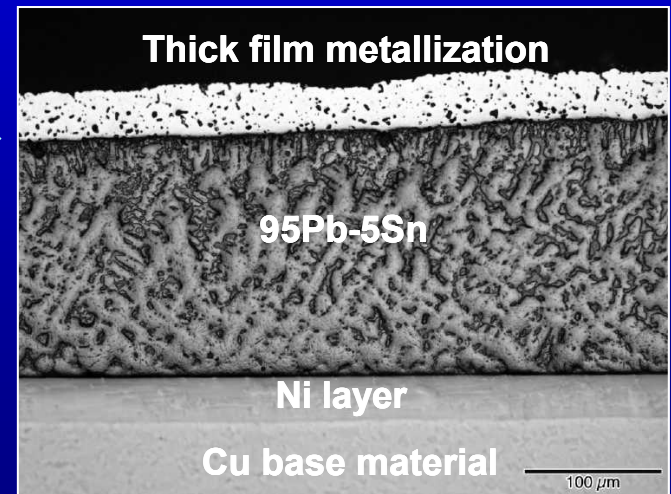
- ◆ High-lead (Pb) solders, defined as having > 85 wt.% Pb, continue to be used extensively to assemble high-temperature electronics.
 - The high-Pb solders remain readily available because of exemption 7a in the RoHS agreement.
 - The solidus temperatures provide an adequate margin for service temperatures $\leq 250^{\circ}\text{C}$.
 - Excellent fatigue performance:
 - Low-cycle, thermal mechanical fatigue
 - High-cycle fatigue – vibration



Introduction

♦ High-lead (Pb) solders ...

- Satisfactory corrosion resistant in the event of exposure to well environments.
- The high-Pb alloys containing 5 – 10 wt.% Sn, In, and Ag are compatible with current assembly infrastructures.
 - Fluxes
 - Heat sources
 - Surface finishes



“ What if ... exemption 7a went away ? “

- ◆ The loss high-Pb solders would pose a challenge for down-hole electronics assemblies.

But ... the challenge is not insurmountable!

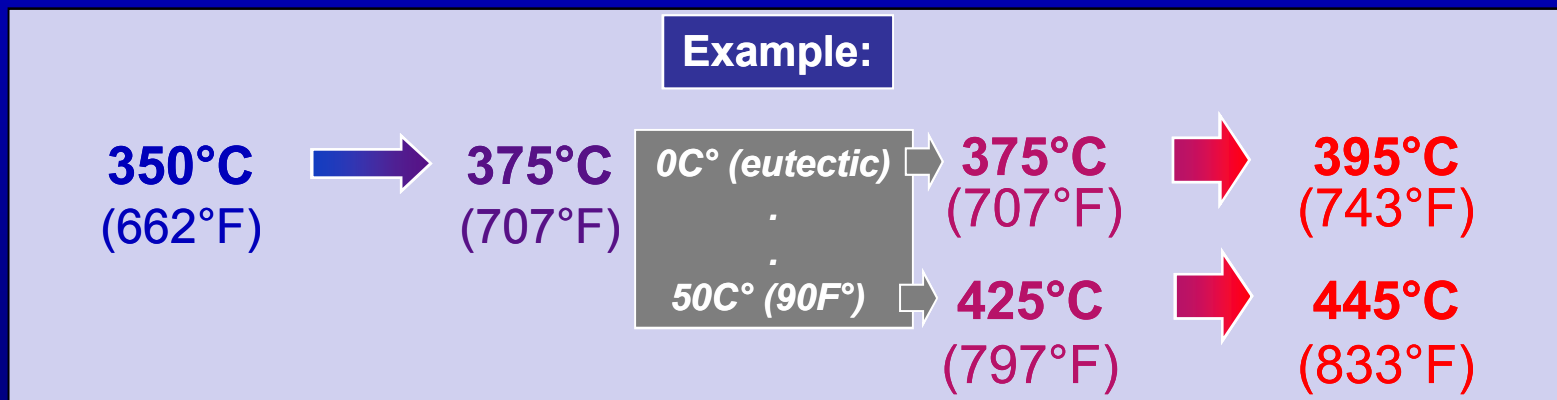
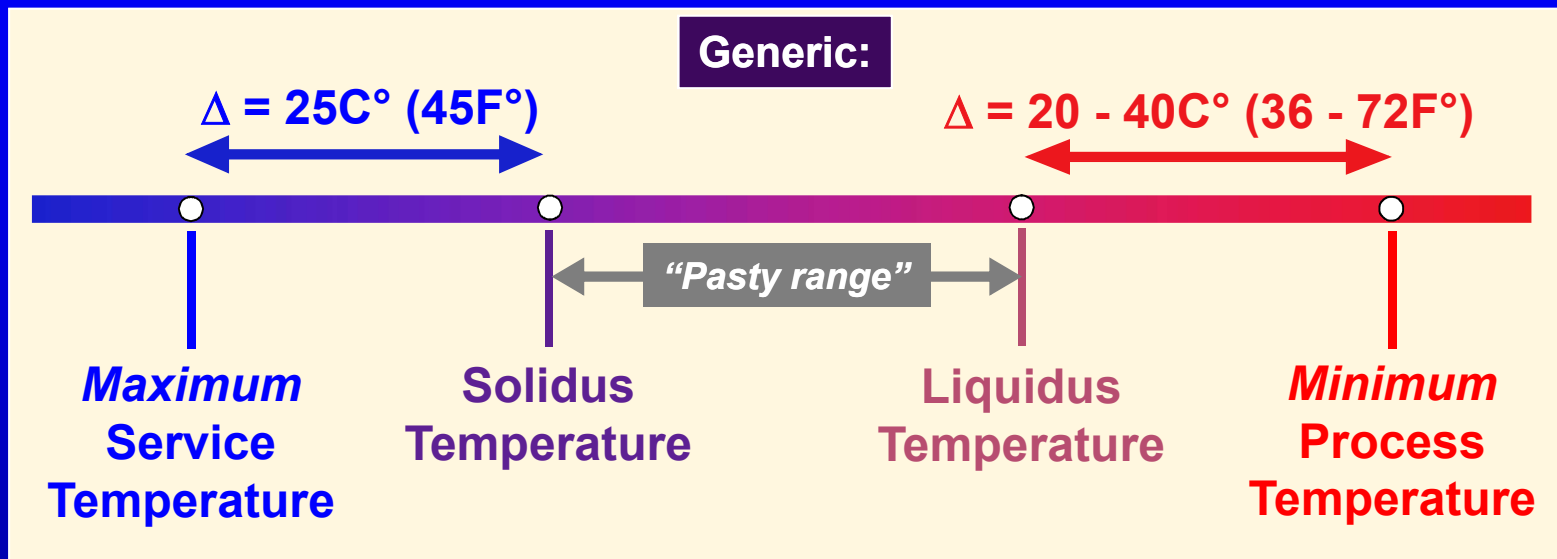
- ◆ Alternative interconnection approaches include:
 - High temperature filler metals
 - Mechanical attachment
 - Transient liquid phase (TLP) bonding
 - Nanoparticle joining techniques
- ◆ Interconnection material choice(s) must satisfy:
 - Assembly processes, infrastructure, and supply chain
 - Reliability requirements



Courtesy of Dept. of Energy

High Temperature Filler Metals

- ◆ Solder alloys must be compatible with the *maximum* service temperature conditions and *minimize* the process temperature.

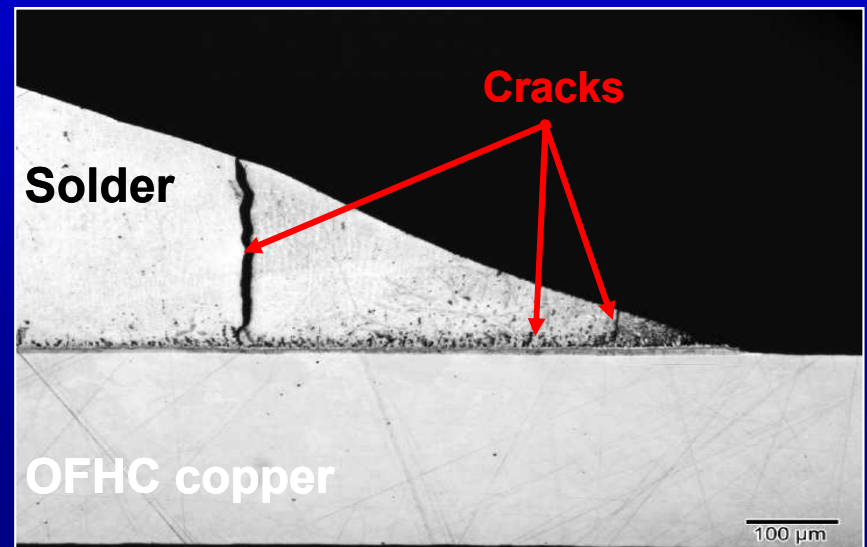


High Temperature Filler Metals

- ◆ There are candidate solder alloys, some commercially-available and others newly engineered, that are being investigated for mechanical properties and solderability performance.
- ◆ Some newly-developed solder alloys are based on **zinc (Zn)**:

$100\text{Zn} \dots T_s = T_l = 420^\circ\text{C} (788^\circ\text{F})$

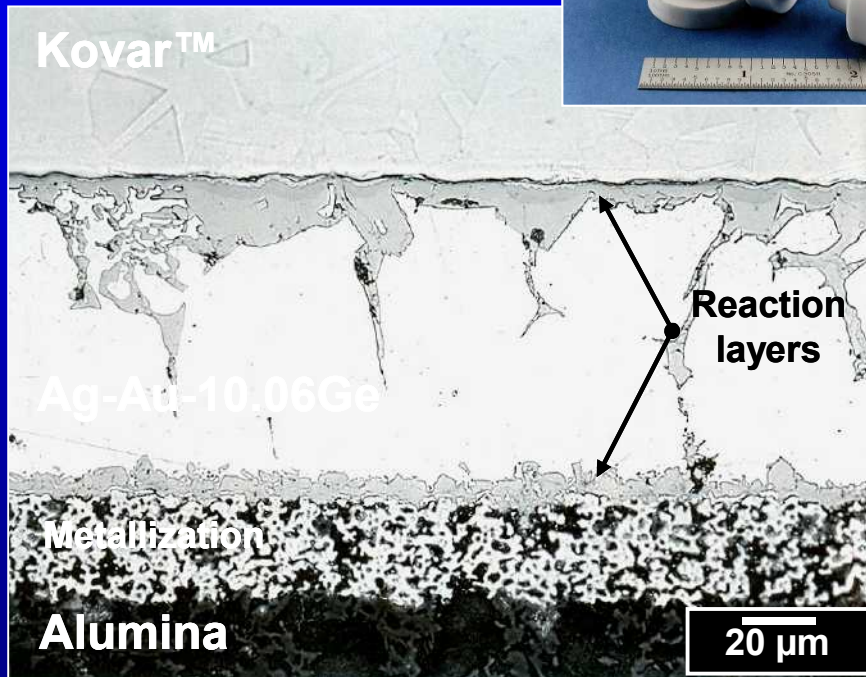
- ◆ At these high process temperatures, controlled atmospheres can replace the flux as the means to reduce surface oxides.
- ◆ Sessile drop experiments provide an initial analysis of the alloy physical metallurgy.



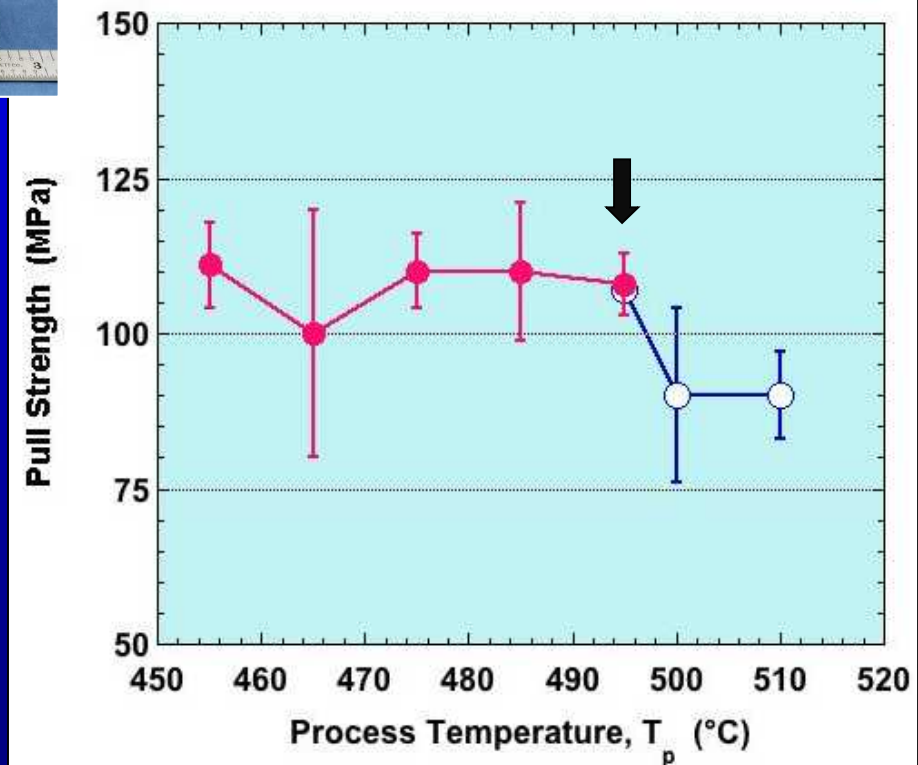
High Temperature Filler Metals

- ◆ The 12.62Ag-77.32Au-10.06Ge (wt.%) alloy (T_s , 400°C to T_l , 450°C) has been considered as a candidate for down-hole applications.

P. Vianco, et al, SMTAI (2013)

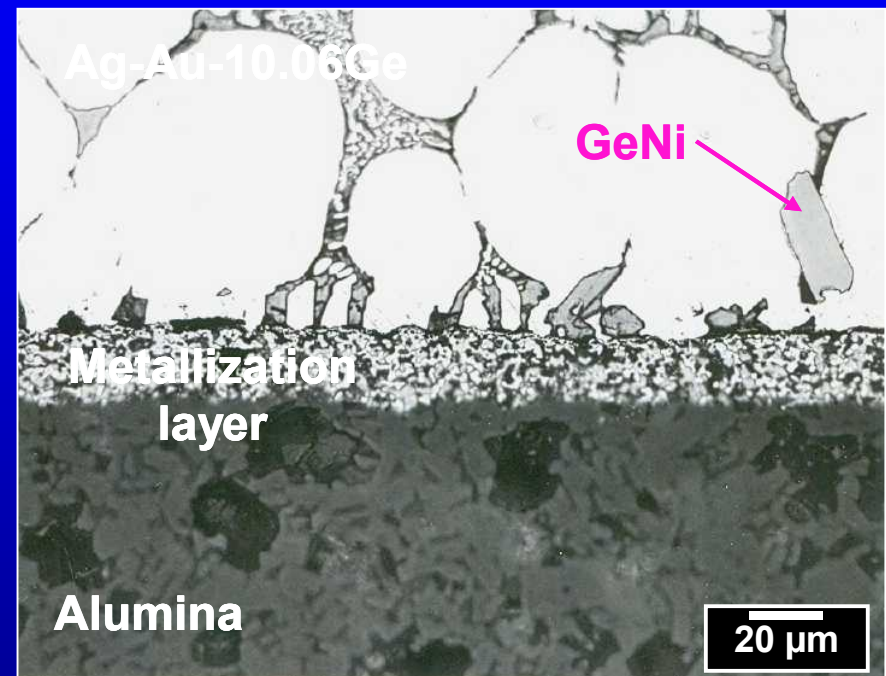
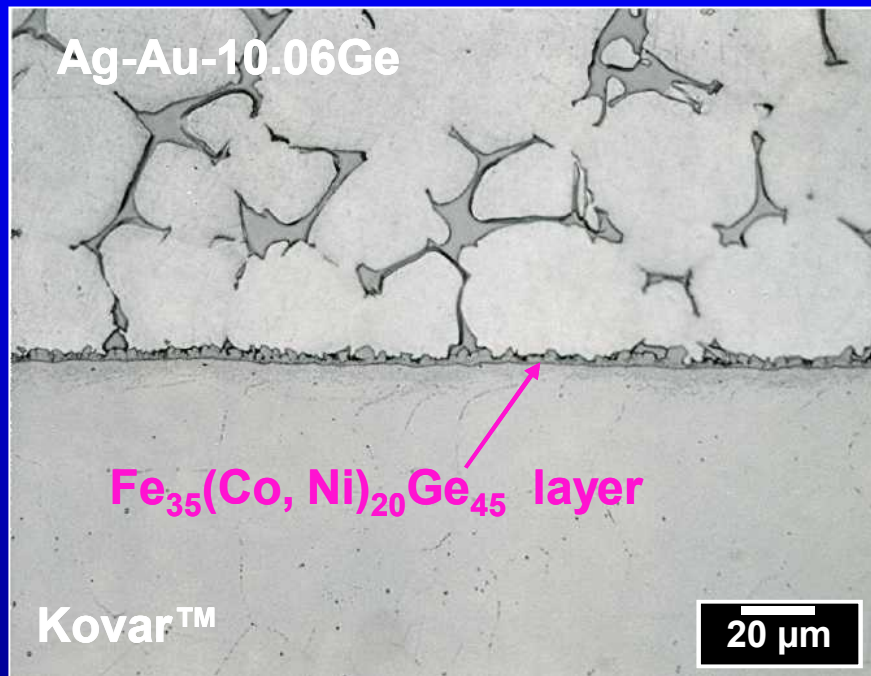


495°C, 5 min



High Temperature Filler Metals

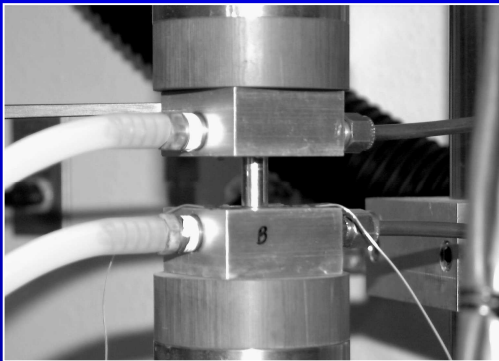
- It is critical to fully understand the **interface microstructures** that develop between high temperature filler metals and the substrate.



- The **Ag-Au-10.06Ge / Kovar** interface is comprised of a 2 – 3 μm reaction layer, $\text{Fe}_{35}(\text{Co}, \text{Ni})_{20}\text{Ge}_{45}$ (as determined by EPMA).
- At the **Ag-Au-10.06Ge / ceramic** interface, the Ni layer was often dissolved into the solder, precipitating as **GeNi phase particles**.

High Temperature Filler Metals

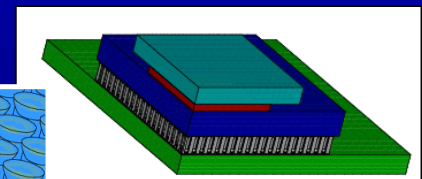
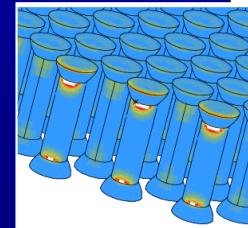
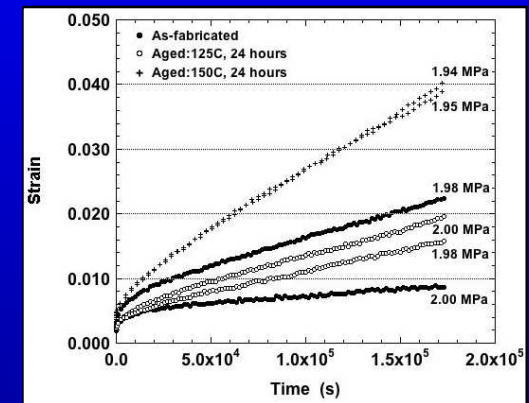
- ◆ High temperature testing will be required in order to obtain both monotonic as well as cyclic (fatigue) mechanical properties for:
 - Screening candidate compositions
 - Input parameters for computational models



Stress-strain tests



Fatigue tests

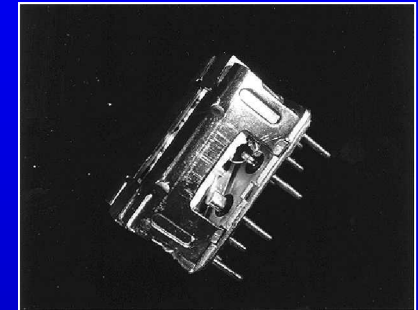


High Temperature Filler Metals

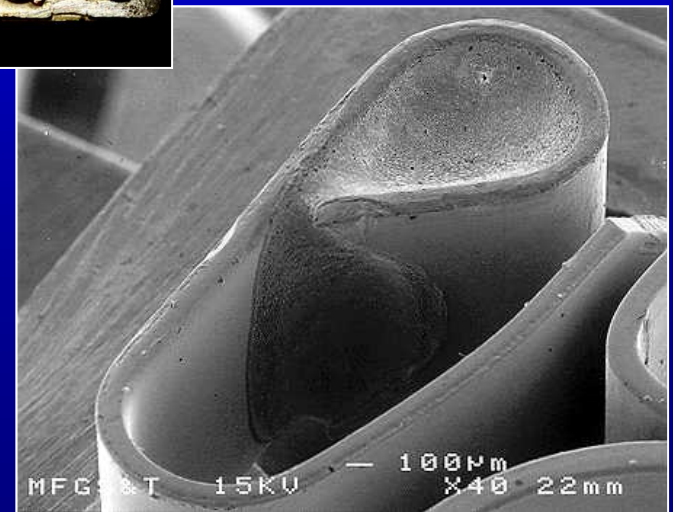
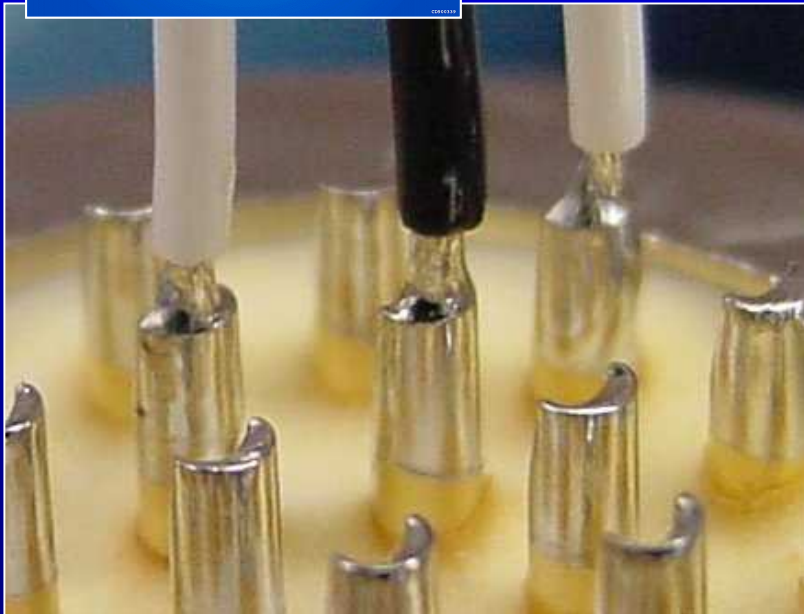
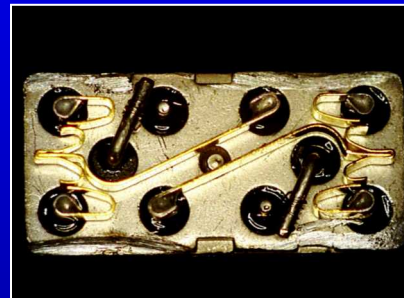
- ◆ New materials sets will be needed for other critical components that include switches, relays, and connectors.



Connector

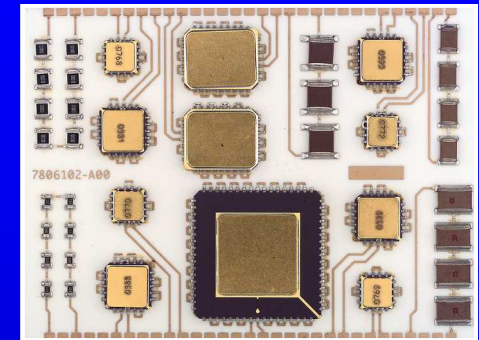


Relay

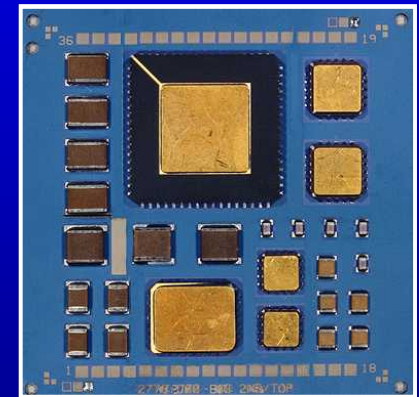


High Temperature Filler Metals

- ◆ Traditional printed circuit board laminates are challenged by the higher temperatures.
- ◆ Ceramic substrates are finding applications:
 - alumina,
 - beryllia,
 - aluminum nitride,
 - low-temperature co-fired ceramic (LTCC).
- ◆ Next-generation substrates include advanced composites and conductors applied by thermal spray or “ink-jet” printing methods.

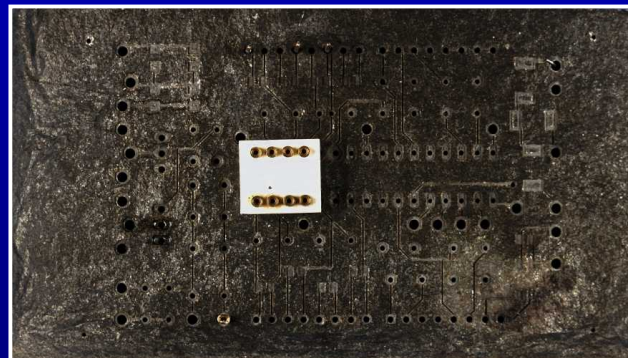


Alumina



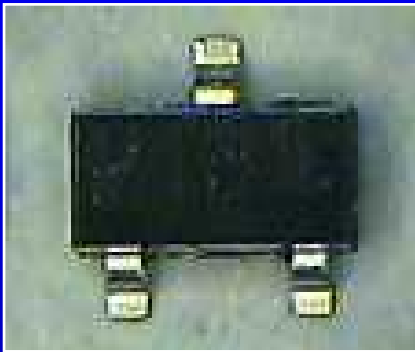
Low-temperature co-fired ceramic (LTCC)

*Advanced
composites*

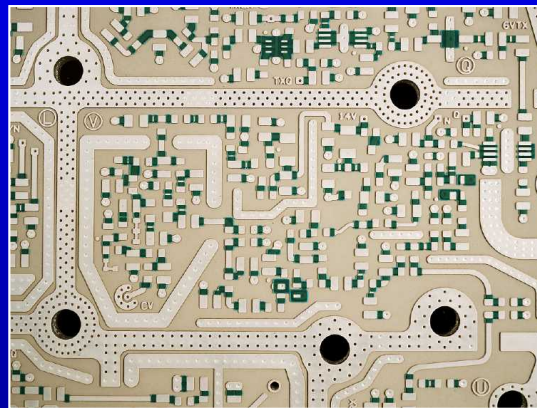


High Temperature Filler Metals

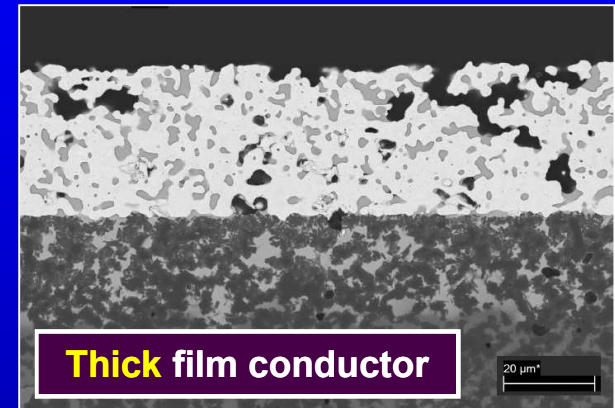
- ◆ **Surface finishes** provide another tool to engineer the solderability of high temperature filler metals on components and substrates.



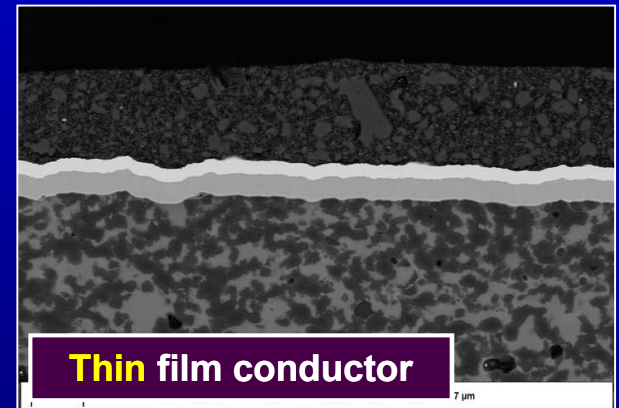
Components



**High-temperature
PCB laminates**



Thick film conductor

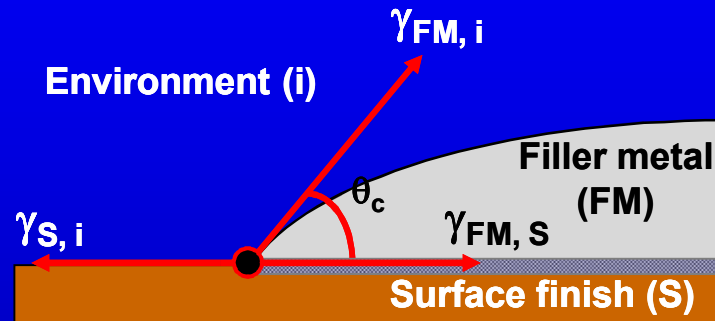


Thin film conductor

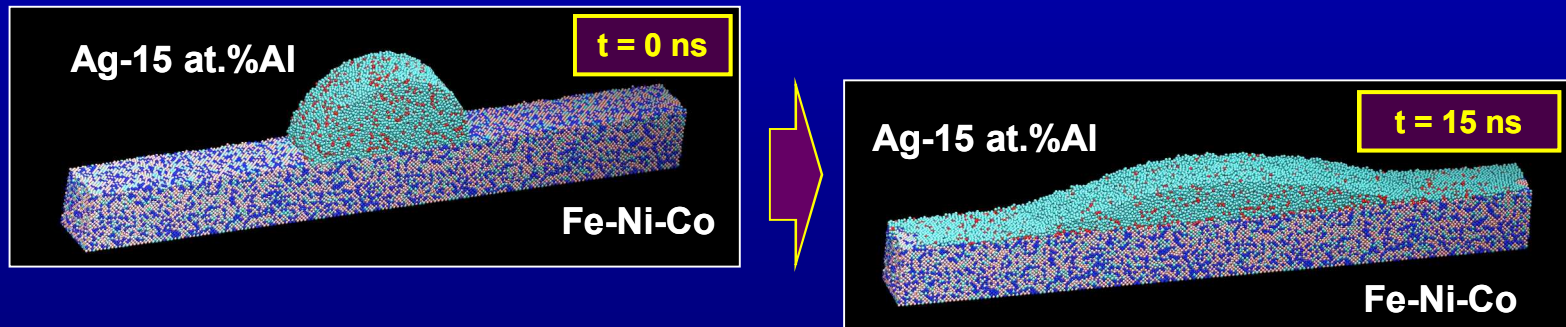
PCB ceramics

High Temperature Filler Metals

- ◆ There is a gap in the understanding of the thermodynamics and rate kinetics of interface reactions relevant to filler metal joining.



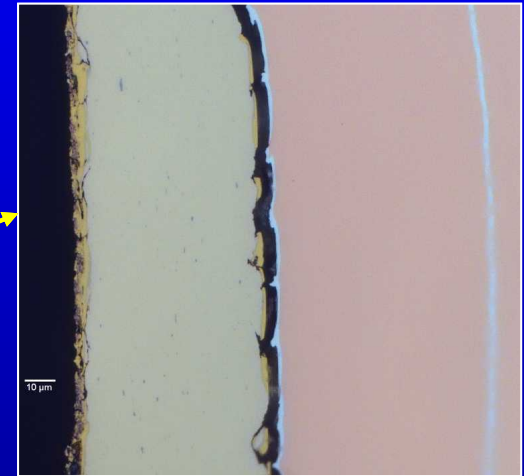
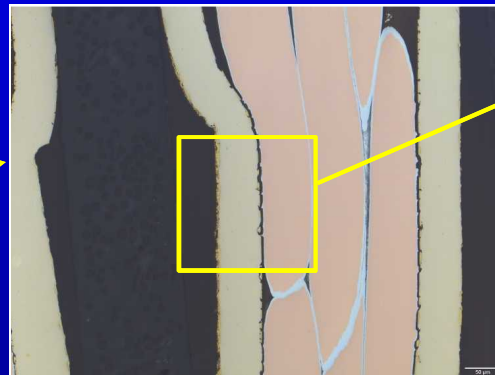
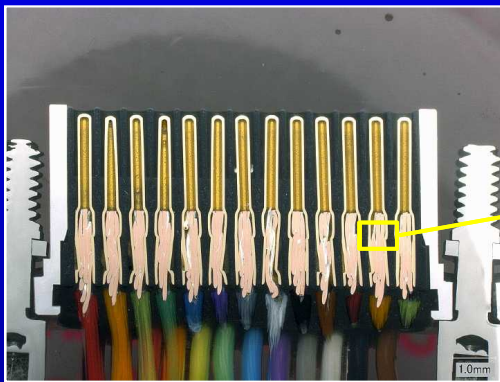
- ◆ **Molecular dynamics simulations** can provide first-order predictions of wetting-and-spreading and interface reactions between molten filler metals and the solid substrate.



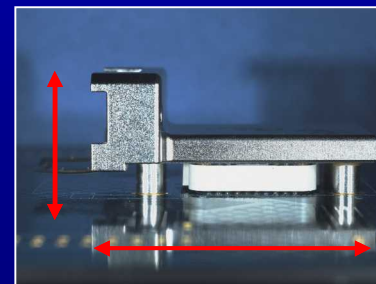
Mechanical Attachments

- ◆ Crimped wires/leads as well as pin-in-socket connections are not preferred for down-hole applications:

- Susceptible to fretting corrosion that increases contact resistance.

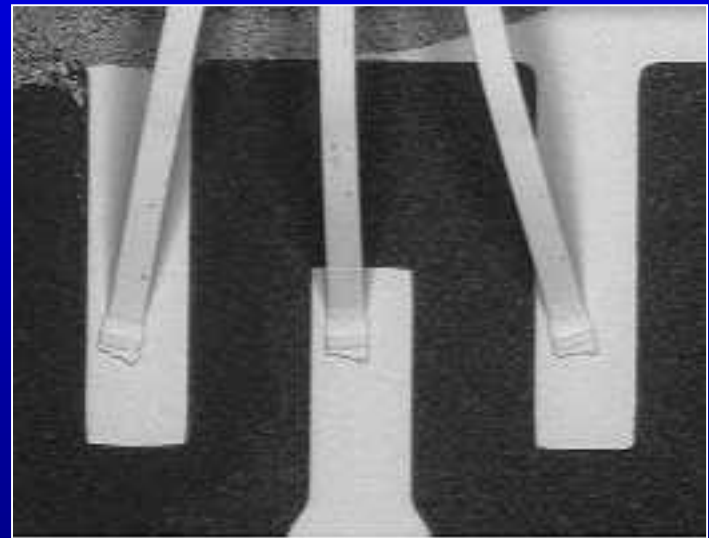


- Sockets and connectors take away miniaturization and increased functionality.



Mechanical Attachments

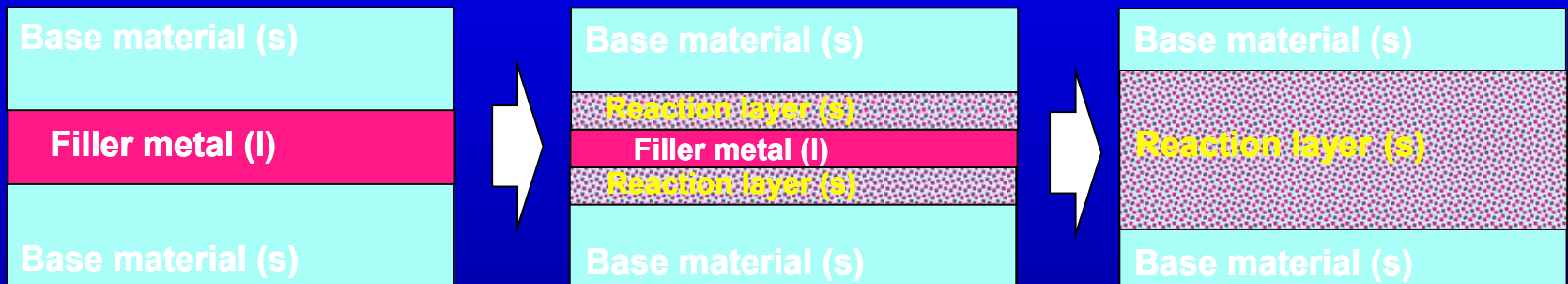
- ◆ On the other hand, thermo-compression and stitch wire and ribbon bonds – both forms of cold-welding – are viable methods:
 - Encapsulations or conformal coatings are recommended to prevent handling and vibration damage.
 - Bond pad and loop height requirements can limit miniaturization.
 - Although not always a consideration in the microelectronics field, an attribute is that these bonds are *reworkable*.



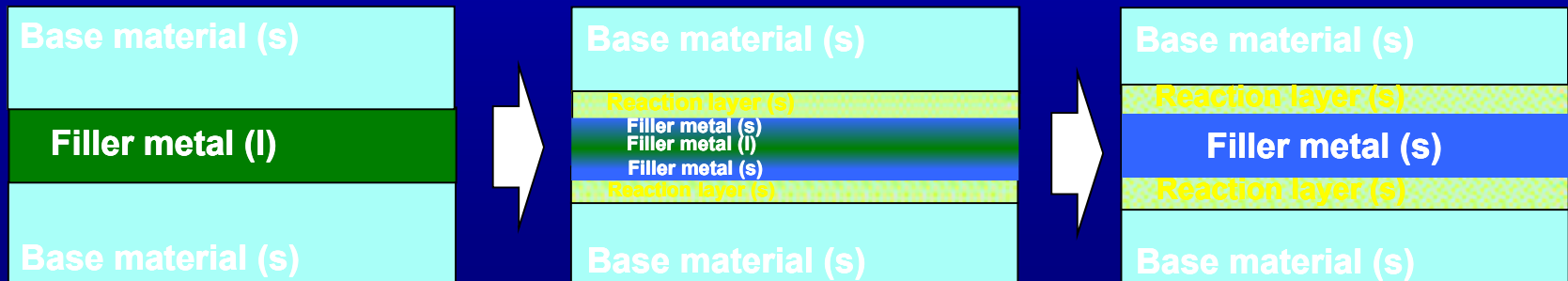
Transient Liquid Phase Bonding (TLP)

- ◆ A methodology that has not received a great deal of attention is transient liquid phase (TLP) bonding:
 - A low temperature process is used to make a higher temperature interconnection.

In-situ TLP

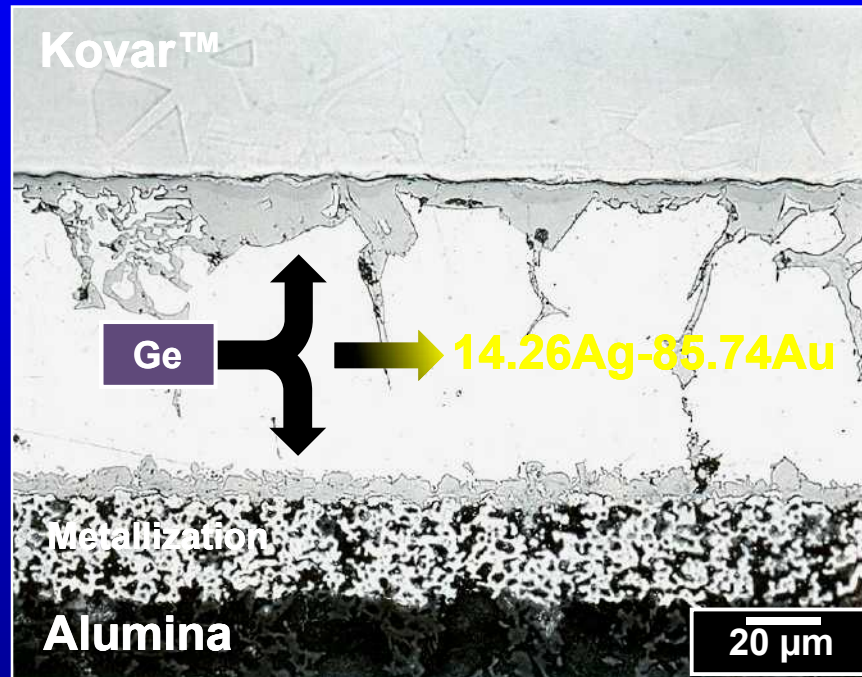


Reverse TLP



Transient Liquid Phase Bonding (TLP)

- ◆ A **reverse transient liquid phase (TLP) process** takes place whereby the Ge constituent is removed from the Ag-Au-Ge alloy.

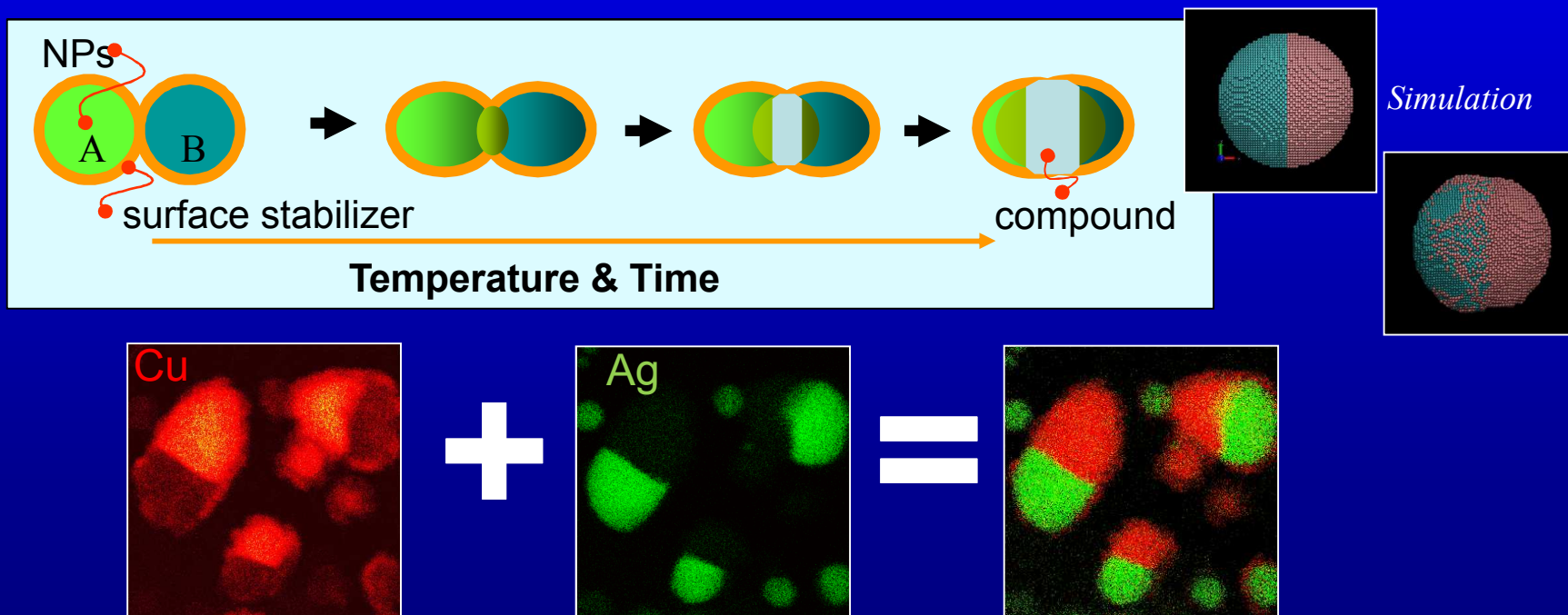


*One (1) 76 μm preform ...
495°C, 5 min*

- ◆ The consequences are:
 - **Binary alloy: 14.26Ag-85.74Au ... $T_s = T_l = 1055^\circ\text{C}$**
 - **Thick, brittle reaction layers formed at both interfaces.**

Nanoparticle Joining Technologies

- ◆ Much like TLP, nanoparticle joining offers this advantage:
 - A low temperature process is used to make a higher temperature interconnection.
- ◆ The objective is a methodology to deliver filler metal alloy nanoparticles to the faying surfaces and form a joint.



Global Perspective

◆ There are engineering challenges:

• Materials

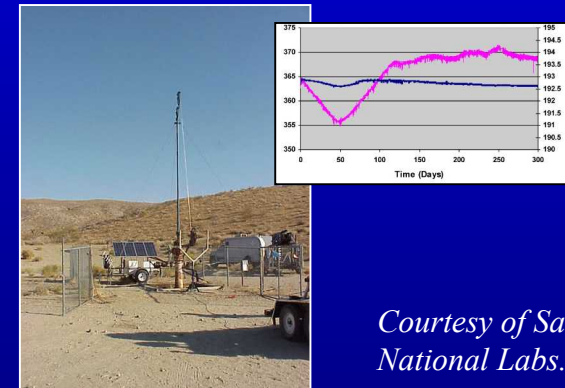
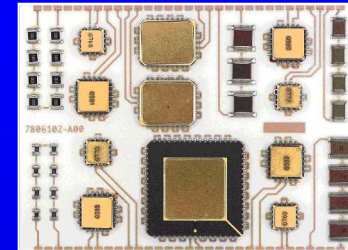
- Interconnection materials
- Base materials
- Surface finishes

• Manufacturing processes

- Low to middle volumes
- Fluxes or controlled atmospheres
- Process windows/margins

• Reliability testing

- Test methods
- Computational modeling
- Field testing

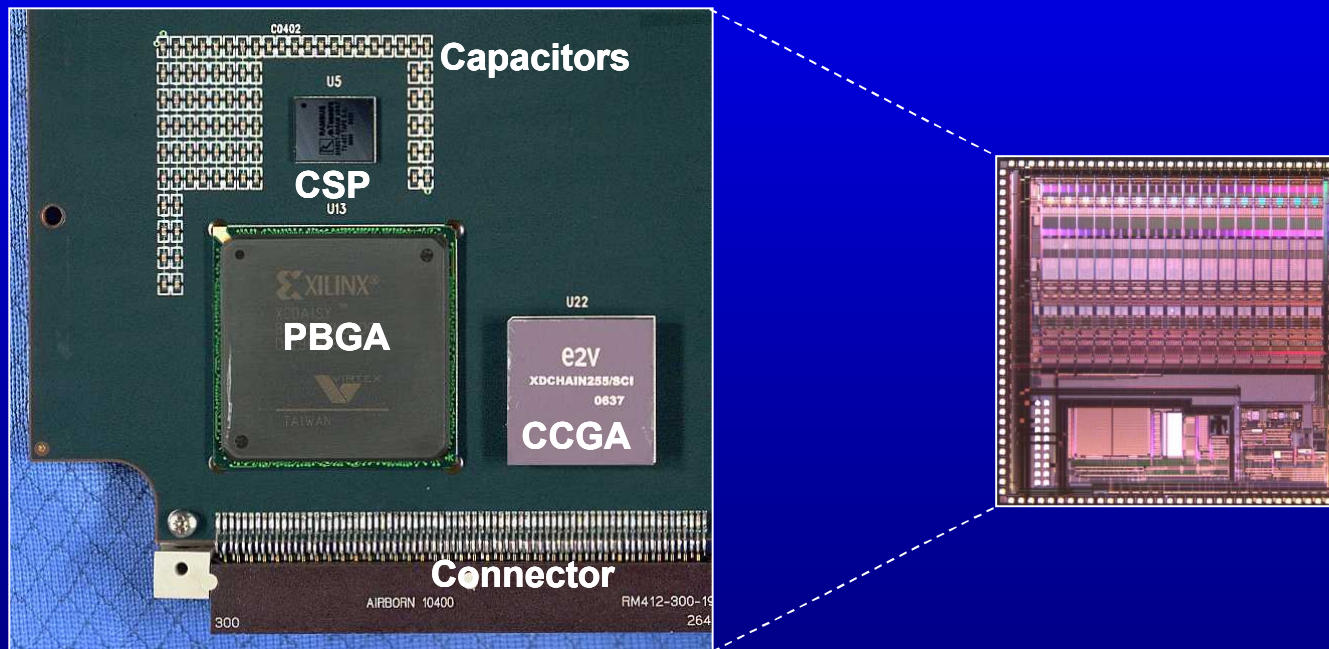


Courtesy of Sandia National Labs.

◆ In the long-run, an alternative interconnection technology must address cost and time-to-market as important considerations.

Global Perspective

- ◆ **Paradigm shift:** Accelerate integration methodologies such as System In a Package (SiP) technologies, to reduce or eliminate discrete components, connectors, etc. and thus, the number of interconnections required in the product.



Summary

- ◆ **Industry costs will continue to grow** that are needed to develop and sustain renewable and non-renewable energy resources.
- ◆ **High temperature electronics provide** a cost-effective tool for the exploration and sustainment of down-hole energy sources.
- ◆ Besides the development of higher melting temperature filler metals, **alternative interconnection technologies are being assessed** that promise to increase operational margins as needed to accommodate down-hole environments.



Courtesy of Dept. of Energy